

PIC24FJ64GB004 Family Silicon Errata and Data Sheet Clarification

The PIC24FJ64GB004 family devices that you have received conform functionally to the current Device Data Sheet (DS39940D), except for the anomalies described in this document.

The silicon issues discussed in the following pages are for silicon revisions with the Device and Revision IDs listed in [Table 1](#). The silicon issues are summarized in [Table 2](#).

The errata described in this document will be addressed in future revisions of the PIC24FJ64GB004 silicon.

Note: This document summarizes all silicon errata issues from all revisions of silicon, previous as well as current. Only the issues indicated in the last column of [Table 2](#) apply to the current silicon revision (**A2**).

Data Sheet clarifications and corrections start on [Page 9](#), following the discussion of silicon issues.

The silicon revision level can be identified using the current version of MPLAB® IDE and Microchip's programmers, debuggers, and emulation tools, which are available at the Microchip corporate web site (www.microchip.com).

For example, to identify the silicon revision level using MPLAB IDE in conjunction with MPLAB ICD 2 or PICKit™ 3:

1. Using the appropriate interface, connect the device to the MPLAB ICD 2 programmer/debugger or PICKit™ 3.
2. From the main menu in MPLAB IDE, select Configure>Select Device, and then select the target part number in the dialog box.
3. Select the MPLAB hardware tool (Debugger>Select Tool).
4. Perform a "Connect" operation to the device (Debugger>Connect). Depending on the development tool used, the part number *and* Device Revision ID value appear in the **Output** window.

Note: If you are unable to extract the silicon revision level, please contact your local Microchip sales office for assistance.

The DEVREV values for the various PIC24FJ64GB004 silicon revisions are shown in [Table 1](#).

TABLE 1: SILICON DEVREV VALUES

Part Number	Device ID ⁽¹⁾	Revision ID for Silicon Revision ⁽²⁾
		A2
PIC24FJ32GB002	4203h	0002h
PIC24FJ32GB004	420Bh	
PIC24FJ64GB002	4207h	
PIC24FJ64GB004	420Fh	

Note 1: The Device IDs (DEVID and DEVREV) are located at the last two implemented addresses in program memory. They are shown in hexadecimal in the format "DEVID DEVREV".

2: Refer to the "PIC24FJ64GA1/GB0 Families Flash Programming Specification" (DS30009934) for detailed information on Device and Revision IDs for your specific device.

PIC24FJ64GB004

TABLE 2: SILICON ISSUE SUMMARY

Module	Feature	Item Number	Issue Summary	Affected Revisions ⁽¹⁾
				A2
Output Compare	Cascaded mode	1.	Cascaded mode does not work as expected.	X
Power-Saving modes	Sleep mode	2.	Transitory increase in IPD under certain conditions.	X
USB	—	3.	Issue with Host mode, low-speed operation.	X
USB	—	4.	CRC errors while using external transceiver.	X
UART	Break Character Generation	5.	Will not generate back-to-back Break characters.	X
Oscillator	Secondary Oscillator Configuration	6.	High-current draw when external signal applied under certain conditions.	X
SPI	Master mode	7.	Spurious transmission and reception of null data on wake-up from Sleep (Master mode).	X
SPI	Master mode	8.	Inaccurate SPITBF flag with high clock divider.	X
Triple (Enhanced) Comparator	—	9.	No interrupt generation with internal band gap reference.	X
Core	Doze mode	10.	Instruction execution glitches following DOZEx bit changes.	X
Oscillator	Two-Speed Start-up	11.	Feature is not functional.	X
A/D Converter	—	12.	Disabled voltage references during Debug mode.	X
Interrupts	INTx	13.	External interrupts missed when writing to INTCON2.	X
Oscillator	—	14.	POSCEN bit does not work with Primary + PLL modes.	X
A/D Converter	—	15.	Module continues to draw current when disabled.	X
Output Compare	Interrupt	16.	Interrupt flag may precede the output pin change under certain circumstances.	X
UART	Transmit	17.	A TX interrupt may occur before the data transmission is complete.	X
USB	Device and Host modes	18.	ACTVIF wake-up behavior differs from previous documentation.	X
USB	Device mode	19.	EPSTALL bit behavior differs from previous documentation.	X
RTCC	LPRC Clock Source	20.	LPRC does not clock RTCC in Deep Sleep under certain circumstances.	X
Deep Sleep	—	21.	POR event may occur on certain Deep Sleep wake-up sequences.	X

Note 1: Only those issues indicated in the last column apply to the current silicon revision.

Silicon Errata Issues

Note: This document summarizes all silicon errata issues from all revisions of silicon, previous as well as current. Only the issues indicated by the shaded column in the following tables apply to the current silicon revision (A2).

1. Module: Output Compare (Cascaded Mode)

When using Cascaded (32-bit) mode, Trigger and Synchronous modes do not work as expected. The even numbered module does not become synchronized to the odd numbered module, resulting in errors in the Most Significant 16 bits of the output. In certain modes, the even numbered module does not generate any output. This behavior is independent of the OCTRIG trigger/sync selection for the even numbered module.

Work around

None.

Affected Silicon Revisions

A2							
X							

2. Module: Power-Saving Modes (Sleep Mode)

When entering Sleep mode, a transitory increase over the specified Power-Down Base Current (IPD) may occur. This has only been observed in some parts and then only under *both* of the following circumstances:

- The operating temperature is below -20°C; and
- Sleep mode is entered within 20 seconds of a POR event.

Following the increase, IPD returns to the normal specified level at 20 seconds after the POR event.

Deep Sleep mode is not affected.

Work around

None

Affected Silicon Revisions

A2							
X							

This issue only applies to devices with date codes prior to 1001NNN, as identified by the package markings.

3. Module: USB

While operating in Host mode and attached to a low-speed device through a full-speed USB hub, the PRE signal may not be generated correctly. This will result in not being able to communicate correctly with the low-speed device.

Work around

Connect low-speed devices directly to the application and not through a USB hub.

Affected Silicon Revisions

A2							
X							

4. Module: USB

When the module is configured to use an external transceiver, the CRC5 value of some packets may be incorrect.

Work around

Use the module's internal transceiver.

Affected Silicon Revisions

A2							
X							

5. Module: UART

The UART module will not generate consecutive Break characters. Trying to perform a back-to-back Break character transmission will cause the UART module to transmit the dummy character used to generate the first Break character, instead of transmitting the second Break character. Break characters are generated correctly if they are followed by non-Break character transmission.

Work around

None.

Affected Silicon Revisions

A2							
X							

6. Module: Oscillator (Secondary Oscillator Configuration)

Under certain circumstances, applying voltages to the comparator inputs, C2INC and C2IND (SOSCO/RA4 and SOSCI/RB4, respectively), may cause the microcontroller's current draw to increase. This happens only when all of the following conditions are met:

- RA4 and RB4 are configured to function as digital I/Os, rather than as Secondary Oscillator pins (SOSCEL<1:0> = 00);
- The pins are configured as digital inputs (TRISA<4> and TRISB<4> = 1); and
- The voltage applied to the pins approaches 1/2 VDD.

This occurs regardless of the signal source. A comparator input voltage or a digital clock input of sufficient amplitude will have the same result.

Work around

If it is necessary to use RA4 and RB4 as comparator inputs, C2INC and C2IND, program the SOSCELx Configuration bits (CW3<9:8>) for one of the Oscillator modes (SOSCEL<1:0> = 11 or 01), rather than as digital I/O.

In addition, use the internal 31 kHz RC Oscillator (LPRC) as the clock source for any systems that might otherwise use the Secondary Oscillator or an external Timer1 source. In addition to Timer1, this includes the RTCC and the Deep Sleep WDT.

Affected Silicon Revisions

A2							
X							

7. Module: SPI (Master Mode)

When operating in Enhanced Buffer Master mode, the module may transmit two bytes or two words of data, with a value of 0h, immediately upon the microcontroller waking up from Sleep mode. At the same time, the module "receives" two words or two bytes of data, also with the value of 0h.

The transmission of null data occurs even if the Transmit Buffer registers are empty prior to the microcontroller entering Sleep mode. The received null data requires that the receive buffer be read twice to clear the "received" data.

This behavior has not been observed when the module is operating in any other mode.

Work around

When operating in Enhanced Buffer Master mode, disable the module (SPIEN = 0) before entering Sleep mode.

Affected Silicon Revisions

A2							
X							

8. Module: SPI (Master Mode)

When operating in Enhanced Buffer Master mode, the Transmit Buffer Full flag, SPITBF, may be cleared before all data in the FIFO buffer has actually been set. This may result in data being overwritten before it can be sent.

This has only been observed when the SPI clock prescalers are configured for a divider of greater than 1:4.

This behavior has not been observed when the module is operating in any other mode.

Work around

Several options are available:

- If possible, use a total clock prescale factor of 1:4 or less.
- Do not use SPITBF to indicate when new data can be written to the buffer. Instead, use the SPIRBF or SPIBEC flags to track the number of bytes actually transmitted.
- If the SPITBF flag must be used, always wait at least one-half SPI clock cycle before writing to the transmit buffer.

Affected Silicon Revisions

A2							
X							

9. Module: Triple (Enhanced) Comparator

When any of the internal band gap options (VBG, VBG/2 or VBG/6) are selected by the voltage reference module as the comparator's CVREF- input, the comparator may not generate an interrupt when a preprogrammed event is detected.

The CVREF+ input works as previously described.

Work around

If it is necessary to use the internal band gap as a reference, do the following:

1. Enable the comparator's output (CMCON<14> = 1) and map the output to a pin with CN functionality or map an INTx function to this same pin. This method only consumes one I/O pin and requires no external connections.
2. Monitor the pin for an interrupt event.

Affected Silicon Revisions

A2							
X							

10. Module: Core (Doze Mode)

Operations that immediately follow any manipulations of the DOZE<2:0> or DOZEN bits (CLKDIV<14:11>) may not execute properly. In particular, for instructions that operate on an SFR, data may not be read properly. Also, bits automatically cleared in hardware may not be cleared if the operation occurs during this interval.

Work around

Always insert a NOP instruction before and after either of the following:

- Enabling or disabling Doze mode by setting or clearing the DOZEN bit
- Before or after changing the DOZE<2:0> bits

Affected Silicon Revisions

A2							
X							

11. Module: Oscillator (Two-Speed Start-up)

Two-Speed Start-up is not functional. Leaving the IESO Configuration bit in its default state (Two-Speed Start-up enabled) may result in unpredictable operation.

Work around

None. Always program the IESO Configuration bit to disable the feature (CW2<15> = 0).

Affected Silicon Revisions

A2							
X							

12. Module: A/D Converter

When using PGEC3 and PGED3 to debug an application, all voltage references will be disabled. This includes VREF+, VREF-, AVDD and AVSS. Any A/D conversion will always equal 03FFh.

Work around

Use either PGEC1/PGED1 or PGEC2/PGED2 to debug any A/D functionality.

Affected Silicon Revisions

A2							
X							

13. Module: Interrupts (INTx)

Writing to the INTCON2 register may cause an external interrupt event (inputs on INT0 through INT2) to be missed. This only happens when the interrupt event and the write event occur during the same clock cycle.

Work around

If this cannot be avoided, write the data intended for INTCON2 to any other register in the interrupt block of the SFR (addresses 0080h to 00E0h); then write the data to INTCON2.

Be certain to write the data to a register not being actively used by the application, or to any of the interrupt flag registers, in order to avoid spurious interrupts. For example, if the interrupts controlled by IEC4 are not being used in the application, the code sequence would be:

```
IEC4 = 0x1E;
INTCON2 = 0x1E;
IEC4 = 0;
```

It is the user's responsibility to determine an appropriate register for the particular application.

Affected Silicon Revisions

A2							
X							

14. Module: Oscillator

The POSCEN bit (OSCCON<2>) has no effect when a Primary Oscillator with PLL mode is selected (COSC<2:0> = 011). If XTPLL, HSPLL or ECPLL Oscillator mode is selected, and the device enters Sleep mode, the Primary Oscillator will be disabled, regardless of the state of the POSCEN bit.

XT, HS and EC Oscillator modes (without the PLL) will continue to operate as expected.

Work around

None.

Affected Silicon Revisions

A2							
X							

15. Module: A/D Converter

Once the A/D module is enabled (AD1CON1<15> = 1), it may continue to draw extra current, even if the module is later disabled (AD1CON1<15> = 0).

Work around

In addition to disabling the module through the ADON bit, set the corresponding PMD bit (ADC1MD, PMD1<0>) to power it down completely.

Disabling the A/D module through the PMD register also disables the AD1PCFG registers, which in turn, affects the state of any port pins with analog inputs. Users should consider the effect on I/O ports and other digital peripherals on those ports when ADC1MD is used for power conservation.

Affected Silicon Revisions

A2							
X							

16. Module: Output Compare (Interrupt)

Under certain circumstances, an output compare match may cause the Output Compare Interrupt Flag (OCxIF) to become set prior to the Change-of-State (COS) of the OCx pin. This has been observed when all of the following are true:

- The module is in One-Shot mode (OCM<2:0> = 001, 010 or 100);
- One of the timer modules is being used as the time base; and
- A timer prescaler other than 1:1 is selected.

If the module is re-initialized by clearing OCM<2:0> after the One-Shot compare, the OCx pin may not be driven as expected.

Work around

After OCxIF is set, allow an interval (in CPU cycles) of at least twice the prescaler factor to elapse before clearing OCM<2:0>. For example, for a prescaler value of 1:8, allow 16 CPU cycles to elapse after the interrupt.

Affected Silicon Revisions

A2							
X							

17. Module: UART

When using `UTXISEL = 01` (interrupt when last character is shifted out of the Transmit Shift Register) and the final character is being shifted out through the Transmit Shift Register, the TX interrupt may occur before the final bit is shifted out.

Work around

If it is critical that the interrupt processing occurs only when all transmit operations are complete, after which the following work around can be implemented:

Hold off the interrupt routine processing by adding a loop at the beginning of the routine that polls the Transmit Shift Register empty bit, as shown in [Example 1](#).

Affected Silicon Revisions

A2							
X							

18. Module: USB (Device and Host Modes)

In previous literature for this module, the `ACTVIF` interrupt flag (`U1OTGIR<4>`) is described as being asserted, based on state changes detected on `D+`, `D-` or `VBUS`, when the microcontroller is in Sleep mode. In actual implementation, state changes on the `RF3/USBID` pin also cause the `ACTVIF` flag to be asserted.

As a result, logic input level changes on `RF3/USBID` may cause `ACTVIF` to be asserted, even in non-OTG applications that do not use the `USBID` function. This may cause the microcontroller to wake up unexpectedly.

Work around

For On-The-Go (OTG)-based applications: No work around is needed.

For non-OTG Device, Host or Dual Role Applications: If `ACTVIF` is used as a wake-up source, it is recommended that the application be designed so that `RF3/USBID` does not see any changes while the microcontroller is in a power-saving mode.

If `RF3/USBID` is not needed in the application, it is recommended to configure it as a digital output.

If the `RF3/USBID` pin is configured as a digital input, ensure that the signal provider does not change the pin state while `ACTVIF` is enabled as a wake-up source. If the pin is used as a general purpose input, which can change while in the USB suspend state, check the `IDIF` flag (`U1OTGIR<7>`), after waking up from an `ACTVIF` event, to determine if the wake-up event was caused by a state change on `RF3/USBID`.

Affected Silicon Revisions

A2							
X							

EXAMPLE 1: DELAYING THE ISR BY POLLING THE TRMT BIT

```
// in UART2 initialization code
...
U2STAbits.UTXISEL0 = 1;           // Set to generate TX interrupt when all
U2STAbits.UTXISEL1 = 0;           // transmit operations are complete.
...

U2TXInterrupt(void)
{
    while(U2STAbits.TRMT==0);      // wait for the transmit buffer to be empty
    ...                            // process interrupt
}
```

19. Module: USB (Device Mode)

In previous literature for this module, the EPSTALL bits (U1EPn<1>) are described as being only stall status indicator bits in Device mode. In actual implementation, the EPSTALL bits function as both status and control bits.

If the EPSTALL bit for Endpoint 'n' is set (either by the SIE hardware or manually in firmware), both the IN and OUT endpoints, associated with the endpoint, will send STALL packets when the endpoint's UOWN bit (BDnSTAT<15>) is also set.

Work around

For Host Applications: No work around is needed as hosts do not send STALL packets.

For Device Mode Applications: When it is necessary to stop sending STALL packets on an endpoint, clear the endpoint's respective BSTALL (BDnSTAT<10>) and EPSTALL bits. If the application firmware was developed based on one of the examples in the Microchip USB framework, this is already the default behavior of the USB stack firmware (except Version 2.8); no further work around is normally needed.

If a Device mode application was based upon Version 2.8 of the USB framework, and the application uses STALL packets on any of the application endpoints (1-15), it is suggested to update the application to the latest version.

Affected Silicon Revisions

A2							
X							

20. Module: RTCC

Under certain circumstances, the RTCC may not be clocked properly when the device is in Deep Sleep mode. This is observed only when all of the following are true:

- The RTCC is using the LPRC as its clock source (RTCOSC = 0);
- The SOSC clock source is disabled (SOSCSEL<1:0> = 00); and
- RA4 is in a logic low state during entry into Deep Sleep, either by being driven low as an output (TRISA4 and LATA4 are both '0'), or being held low as an input.

Work around

The issue does not occur if RA4 is maintained in a logic high state while the device is in Deep Sleep. This can be done by driving the pin high as an output (TRISA4 = 0, LATA4 = 1) or driving the pin to logic high from an external source while it is configured as an input.

The issue also does not occur if the SOSC is configured for one of the Crystal Driver modes (SOSCSEL<1:0> = x1).

Either method can be used with the same effect.

Affected Silicon Revisions

A2							
X							

21. Module: Deep Sleep

If the VDDCORE voltage happens to be at a level near 1.9V just prior to the Deep Sleep wake-up event source arriving, an extraneous POR event may occur during the wake-up sequence.

Work around

None.

Affected Silicon Revisions

A2							
X							

Data Sheet Clarifications

The following typographic corrections and clarifications are to be noted for the latest version of the Device Data Sheet (DS39940D):

Note: Corrections are shown in **bold**. Where possible, the original bold text formatting has been removed for clarity.

1. Module: Guidelines for Getting Started with 16-Bit Microcontrollers

Section 2.4 Voltage Regulator Pins (ENVREG/DISVREG and VCAP/VDDCORE) has been replaced with a new and more detailed section. The entire text follows:

2.4 Voltage Regulator Pins (ENVREG/DISVREG and VCAP/VDDCORE)

Note: This section applies only to PIC24FJ devices with an on-chip voltage regulator.

The on-chip voltage regulator enable/disable pin (ENVREG or DISVREG, depending on the device family) must always be connected directly to either a supply voltage or to ground. The particular connection is determined by whether or not the regulator is to be used:

- For ENVREG, tie to VDD to enable the regulator, or to ground to disable the regulator
- For DISVREG, tie to ground to enable the regulator or to VDD to disable the regulator

Refer to **Section 26.2 “On-Chip Voltage Regulator”** for details on connecting and using the on-chip regulator.

When the regulator is enabled, a low-ESR ($< 5\Omega$) capacitor is required on the VCAP/VDDCORE pin to stabilize the voltage regulator output voltage. The VCAP/VDDCORE pin must not be connected to VDD and must use a capacitor of 10 μF connected to ground. The type can be ceramic or tantalum. Suitable examples of capacitors are shown in [Table 2-1](#). Capacitors with equivalent specifications can be used.

Designers may use [Figure 2-3](#) to evaluate ESR equivalence of candidate devices.

The placement of this capacitor should be close to VCAP/VDDCORE. It is recommended that the trace length not exceed 0.25 inch (6 mm). Refer to **Section 29.0 “Electrical Characteristics”** for additional information.

When the regulator is disabled, the VCAP/VDDCORE pin must be tied to a voltage supply at the VDDCORE level. Refer to **Section 29.0 “Electrical Characteristics”** for information on VDD and VDDCORE.

FIGURE 2-3 FREQUENCY vs. ESR PERFORMANCE FOR SUGGESTED VCAP

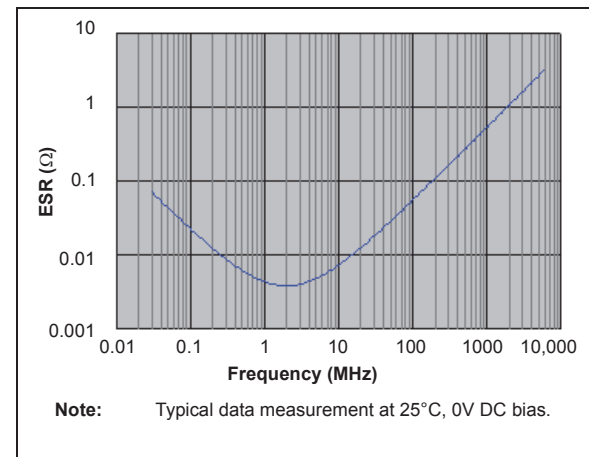


TABLE 2-1 SUITABLE CAPACITOR EQUIVALENTS

Make	Part #	Nominal Capacitance	Base Tolerance	Rated Voltage	Temp. Range
TDK	C3216X7R1C106K	10 μF	$\pm 10\%$	16V	-55 to 125°C
TDK	C3216X5R1C106K	10 μF	$\pm 10\%$	16V	-55 to 85°C
Panasonic	ECJ-3YX1C106K	10 μF	$\pm 10\%$	16V	-55 to 125°C
Panasonic	ECJ-4YB1C106K	10 μF	$\pm 10\%$	16V	-55 to 85°C
Murata	GRM32DR71C106KA01L	10 μF	$\pm 10\%$	16V	-55 to 125°C
Murata	GRM31CR61C106KC31L	10 μF	$\pm 10\%$	16V	-55 to 85°C

2.4.1 CONSIDERATIONS FOR CERAMIC CAPACITORS

In recent years, large value, low-voltage surface mount ceramic capacitors have become very cost effective in sizes up to a few tens of microfarad. The low-ESR, small physical size and other properties make ceramic capacitors very attractive in many types of applications.

Ceramic capacitors are suitable for use with the internal voltage regulator of this microcontroller. However, some care is needed in selecting the capacitor to ensure that it maintains sufficient capacitance over the intended operating range of the application.

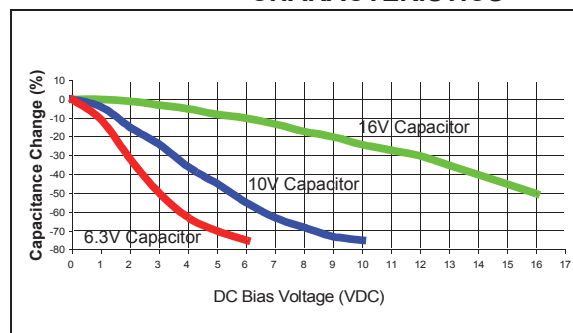
Typical low cost, 10 μF ceramic capacitors are available in X5R, X7R and Y5V dielectric ratings (other types are also available, but are less common). The initial tolerance specifications for these types of capacitors are often specified as $\pm 10\%$ to $\pm 20\%$ (X5R and X7R), or $-20\%/+80\%$ (Y5V). However, the effective capacitance that these capacitors provide in an application circuit will also vary based on additional factors, such as the applied DC bias voltage and the temperature. The total in-circuit tolerance is, therefore, much wider than the initial tolerance specification.

The X5R and X7R capacitors typically exhibit satisfactory temperature stability (ex: $\pm 15\%$ over a wide temperature range, but consult the manufacturer's data sheets for exact specifications). However, Y5V capacitors typically have extreme temperature tolerance specifications of $+22\%/-82\%$. Due to the extreme temperature tolerance, a 10 μF nominal rated Y5V type capacitor may not deliver enough total capacitance to meet minimum internal voltage regulator stability and transient response requirements. Therefore, Y5V capacitors are not recommended for use with the internal voltage regulator if the application must operate over a wide temperature range.

In addition to temperature tolerance, the effective capacitance of large value ceramic capacitors can vary substantially, based on the amount of DC voltage applied to the capacitor. This effect can be very significant, but is often overlooked or is not always documented.

A typical DC bias voltage vs. capacitance graph for 16V, 10V and 6.3V rated capacitors is shown in Figure 2-4.

FIGURE 2-4 DC BIAS VOLTAGE vs. CAPACITANCE CHARACTERISTICS



When selecting a ceramic capacitor to be used with the internal voltage regulator, it is suggested to select a high-voltage rating, so that the operating voltage is a small percentage of the maximum rated capacitor voltage. For example, choose a ceramic capacitor rated at 16V for the 2.5V core voltage. Suggested capacitors are shown in Table 2-1.

2. Module: Electrical Characteristics

Changes, shown in bold, have been made to the DC10 and DC18 rows in [Table 29-3](#) (changes in **bold**; bold in original removed for clarity). The updated table is shown below:

TABLE 29-3 DC CHARACTERISTICS: TEMPERATURE AND VOLTAGE SPECIFICATIONS

DC CHARACTERISTICS			Standard Operating Conditions: 2.0V to 3.6V (unless otherwise stated) Operating temperature $0^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for Industrial $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ for Extended				
Param No.	Symbol	Characteristic	Min	Typ ⁽¹⁾	Max	Units	Conditions
Operating Voltage							
DC10	Supply Voltage						
	VDD		VBORMIN	—	3.6	V	Regulator enabled
	VDD		VDDCORE	—	3.6	V	Regulator disabled
	VDDCORE		2.0	—	2.75	V	Regulator disabled
DC12	VDR	RAM Data Retention Voltage ⁽²⁾	1.5	—	—	V	
DC16	VPOR	VDD Start Voltage to Ensure Internal Power-on Reset Signal	Vss	—	—	V	
DC17	SVDD	VDD Rise Rate to Ensure Internal Power-on Reset Signal	0.05	—	—	V/ms	0-3.3V in 0.1s 0-2.5V in 60 ms
DC18	VBOR	Brown-out Reset Voltage	1.80	2.03	2.2	V	16 MHz (8 MIPS) operation is supported until BOR is active

Note 1: Data in "Typ" column is at 3.3V, 25°C unless otherwise stated. Parameters are for design guidance only and are not tested.

Note 2: This is the limit to which VDD can be lowered without losing RAM data.

PIC24FJ64GB004

3. Module: Electrical Specifications

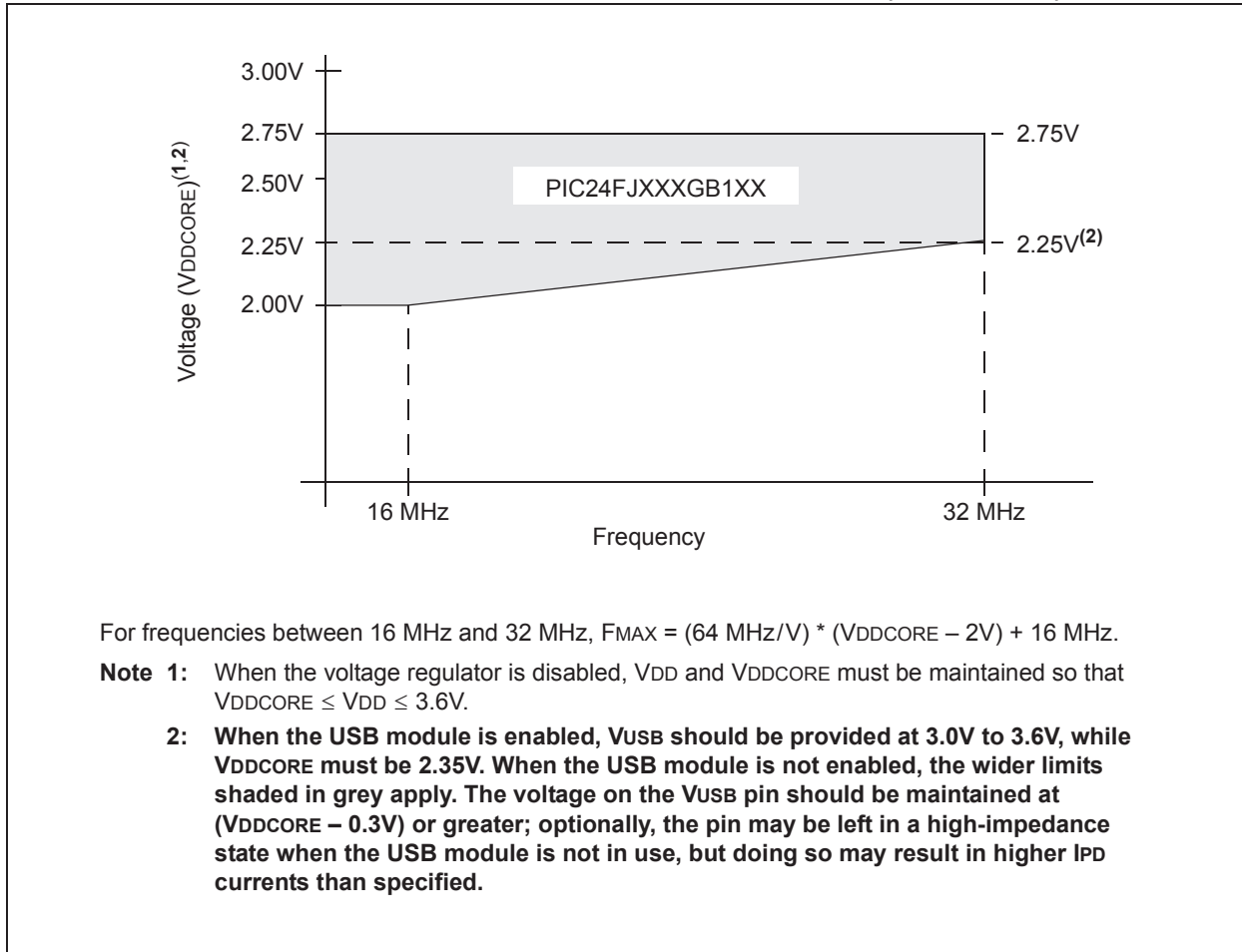
The “Absolute Maximum Ratings” listed on Page 305 are amended by adding the following specification:

Voltage on VUSB with respect to VSS.....
(VDDCORE – 0.3V) to 4.0V

4. Module: Electrical Specifications (DC Characteristics)

Figure 29-1 (“PIC24FJ256GB110 Family Voltage-Frequency Graph”) is amended by adding an additional footnote. The updated figure is shown below (changes in **bold**; bold in original removed for clarity).

FIGURE 29-1: PIC24FJ64GB004 VOLTAGE-FREQUENCY GRAPH (INDUSTRIAL)



5. Module: Electrical Specifications (DC Characteristics)

Table 29-3 ("DC Characteristics: Temperature and Voltage Specifications") is amended by adding a new specification, **V_{USB}**, and an explanatory footnote. The changes are shown below in **bold** (bold text in original removed for clarity).

**TABLE 29-3: DC CHARACTERISTICS: TEMPERATURE AND VOLTAGE SPECIFICATIONS
(PARTIAL REPRESENTATION)**

DC CHARACTERISTICS			Standard Operating Conditions: 2.0V to 3.6V (unless otherwise stated) Operating temperature $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for Industrial				
Param No.	Symbol	Characteristic	Min	Typ ⁽¹⁾	Max	Units	Conditions
Operating Voltage							
	V_{USB}	USB Supply Voltage	3.0	3.3	3.6	V	USB module enabled⁽³⁾

- Note 1: Data in "Typ" column is at 3.3V, 25°C unless otherwise stated. Parameters are for design guidance only and are not tested.
- 2: This is the limit to which V_{DD} can be lowered without losing RAM data.
- 3: **V_{USB} should always be maintained at V_{DD} or greater when the USB module is enabled. The V_{USB} pin may be left in a high-impedance state when the USB module is disabled and pins, RB11 and RB12, will not be used as general purpose inputs, but doing so may result in higher I_{PD} currents than specified.**

PIC24FJ64GB004

6. Module: Electrical Specifications

Table 29-7 (I/O Pin Input Specifications) is amended by the addition of the following new specifications:

- D131 (Maximum Load Current for Digital High Detection with Internal Pull-up)
- D160 (Input Injection Currents)

The new specifications, and accompanying new Footnotes 5 through 9, are shown below (additions in **bold**; bold in existing text removed for clarity).

7. Module: Packaging Information

Section 30.0 “Packaging Information” omits the drawings for 28-pin SOIC packages (7.5 mm, type SO), which are a valid packaging option for this device family. The applicable Microchip drawings (C04-052C, two sheets, and C04-2052A) are added to the section. They appear on the following pages.

Additionally, PIC24FJ64GB004 family devices are not available in 24-pin packages. The 24-pin SOIC drawing (C04-025B) is to be disregarded.

TABLE 29-7: DC CHARACTERISTICS: I/O PIN INPUT SPECIFICATIONS (PARTIAL PRESENTATION)

DC CHARACTERISTICS			Standard Operating Conditions: 3.0V to 3.6V (unless otherwise stated) Operating temperature $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for Industrial $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ for Extended				
Param.	Symbol	Characteristic	Min.	Typ ⁽¹⁾	Max.	Units	Conditions
D131	IPU	Maximum Load Current for Digital High Detection with Internal Pull-up	—	—	30	μA	$V_{DD} = 2.0\text{V}$
			—	—	100	μA	$V_{DD} = 3.3\text{V}$
D160a	IICL	Input Low Injection Current	0	—	-5 ^(5,8)	mA	All pins except V_{DD} , V_{SS} , AV_{DD} , AV_{SS} , $MCLR$, V_{CAP} , $RB14$, $SOSCI$, $SOSCO$, $D+$, $D-$, V_{USB} and V_{BUS}
D160b	IICH	Input High Injection Current	0	—	+5 ^(6,7,8)	mA	All pins except V_{DD} , V_{SS} , AV_{DD} , AV_{SS} , $MCLR$, V_{CAP} , $RB14$, $SOSCI$, $SOSCO$, $D+$, $D-$, V_{USB} and V_{BUS} , and all 5V tolerant pins ⁽⁷⁾
D160c	ΣI_{ICT}	Total Input Injection Current (sum of all I/O and control pins)	-20 ⁽⁹⁾	—	+20 ⁽⁹⁾	mA	Absolute instantaneous sum of all $\pm$ input injection currents from all I/O pins ($ I_{ICL} + I_{ICH} $) $\leq \Sigma I_{ICT}$

Note 1: (existing footnote)

2: (existing footnote)

3: (existing footnote)

4: (existing footnote)

5: Parameter characterized but not tested.

6: Non-5V tolerant pins V_{IH} source $> (V_{DD} + 0.3)$, 5V tolerant pins V_{IH} source $> 5.5\text{V}$. Characterized but not tested.

7: Digital 5V tolerant pins cannot tolerate any “positive” input injection current from input sources greater than 5.5V.

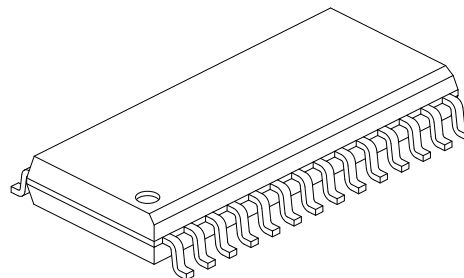
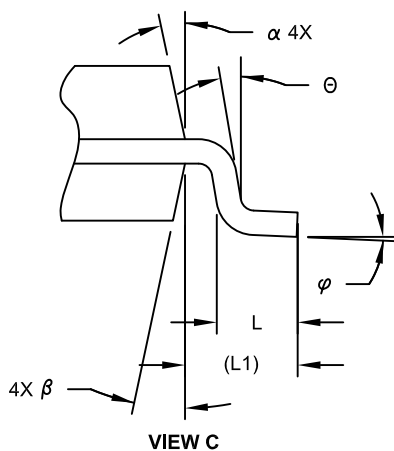
8: Injection currents $> |0|$ can affect the performance of all analog peripherals (e.g., A/D, comparators, internal band gap reference, etc.)

9: Any number and/or combination of I/O pins not excluded under IICL or IICH conditions are permitted provided the mathematical “absolute instantaneous” sum of the input injection currents from all pins do not exceed the specified limit. Characterized but not tested.

PIC24FJ64GB004

28-Lead Plastic Small Outline (SO) - Wide, 7.50 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	28		
Pitch	e	1.27 BSC		
Overall Height	A	-	-	2.65
Molded Package Thickness	A2	2.05	-	-
Standoff §	A1	0.10	-	0.30
Overall Width	E	10.30 BSC		
Molded Package Width	E1	7.50 BSC		
Overall Length	D	17.90 BSC		
Chamfer (Optional)	h	0.25	-	0.75
Foot Length	L	0.40	-	1.27
Footprint	L1	1.40 REF		
Lead Angle	θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.18	-	0.33
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

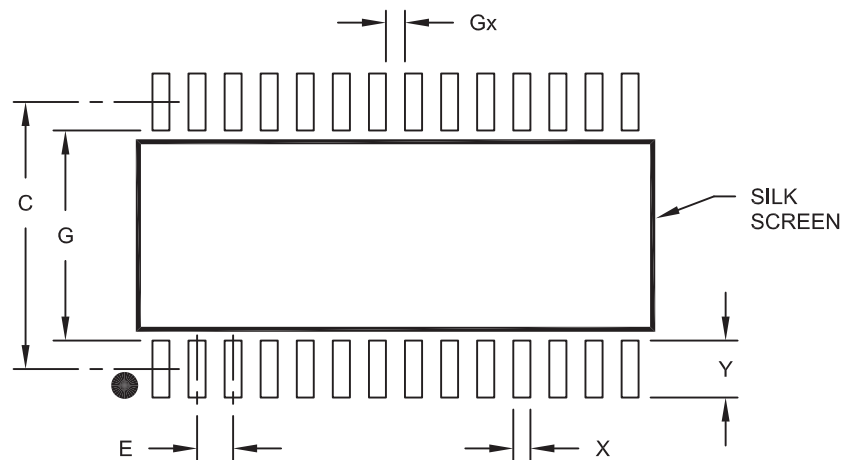
Notes:

- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.
- Datums A & B to be determined at Datum H.

Microchip Technology Drawing C04-052C Sheet 2 of 2

28-Lead Plastic Small Outline (SO) - Wide, 7.50 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	1.27 BSC		
Contact Pad Spacing	C		9.40	
Contact Pad Width (X28)	X			0.60
Contact Pad Length (X28)	Y			2.00
Distance Between Pads	Gx	0.67		
Distance Between Pads	G	7.40		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2052A

PIC24FJ64GB004

8. Module: Electrical Characteristics

In Table 29-19, Parameter F20 has been amended with two temperature ranges. The changes are shown below in **bold** (bold text in original removed for clarity).

TABLE 29-19: INTERNAL RC OSCILLATOR ACCURACY

AC CHARACTERISTICS		Standard Operating Conditions: 2.0V to 3.6V (unless otherwise stated) Operating temperature -40°C ≤ TA ≤ +85°C for Industrial -40°C ≤ TA ≤ +125°C for Extended				
Param No.	Characteristic	Min	Typ	Max	Units	Conditions
F20	FRC Accuracy @ 8 MHz^(1,3)	-1.5	±0.25	1.0	%	-10°C ≤ TA ≤ +85°C, 3.0V ≤ VDD ≤ 3.6V
	FRC Accuracy @ 8 MHz⁽³⁾	-2.0	±0.25	2.0	%	-40°C ≤ TA ≤ -10°C, 3.0V ≤ VDD ≤ 3.6V
F21	LPRC Accuracy @ 31 kHz ⁽²⁾	-15	—	15	%	-40°C ≤ TA ≤ +85°C, 3.0V ≤ VDD ≤ 3.6V

- Note 1: Frequency calibrated at 25°C and 3.3V. OSCUN bits can be used to compensate for temperature drift.
2: Change of LPRC frequency as VDD changes.
3: To achieve this accuracy, physical stress applied to the microcontroller package (ex: by flexing the PCB) must be kept to a minimum.

APPENDIX A: DOCUMENT REVISION HISTORY

Rev A Document (10/2009)

Initial release of this document; issued for revision A2. Includes silicon issues 1 (Output Compare – Cascaded Mode), 2 (Power-Saving Modes, Sleep Mode), 3-4 (USB) and 5 (UART).

Rev B Document (2/2010)

Adds new silicon issues 6 (Oscillator – Secondary Oscillator Configuration), 7 and 8 (SPI – Master Mode), 9 (Triple (Enhanced) Comparator), 10 (Core – Doze Mode) and 11 (Oscillator – Two-Speed Start-up) to silicon revision A2.

Rev C Document (2/2010)

Update to silicon issue 2 (Power-Saving Modes – Sleep Mode).

Rev D Document (8/2010)

Adds new silicon issues 12 (A/D Converter), 13 (Interrupts – INTx) 14 (Oscillator) and 15 (A/D Converter) to silicon revision A2.

Rev E Document (9/2010)

Revised silicon issue 15 (A/D Converter) to reflect updated definition of issues. Added data sheet clarification issues 1 (Guidelines For Getting Started with 16-Bit Microcontrollers) and 2 (Electrical Characteristics).

Rev F Document (11/2010)

Revised data sheet clarification issue 2 (Electrical Characteristics).

Rev G Document (04/2011)

Added data sheet clarification issues 3, 4 and 5 (Electrical Characteristics). No new silicon issues added.

Rev H Document (11/2011)

Added silicon issues 16 (UART – Transmit), 17 (Output Compare – Interrupt), 18 (USB – Device and Host Modes) and 19 (USB – Device Mode) to silicon revision A2.

Added data sheet clarification issues 6 (Electrical Characteristics) and 7 (Packaging Information).

Revised data sheet clarification issue 2 (Electrical Characteristics) to update specification DC18 (BOR) (now 1.90V Minimum, 2.2V Maximum).

Rev J Document (6/2012)

Added data sheet clarification issue 8 (Electrical Characteristics).

Rev K Document (4/2013)

Added silicon issue 20 (RTCC) and changed the DC18 VBOR min. value in data sheet clarification 2 (Electrical Characteristics) from 1.90V to 1.80V.

Rev L Document (10/2018)

Added silicon issue 21 (Deep Sleep).

PIC24FJ64GB004

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.

QUALITY MANAGEMENT SYSTEM
CERTIFIED BY DNV
== ISO/TS 16949 ==

Trademarks

The Microchip name and logo, the Microchip logo, AnyRate, AVR, AVR logo, AVR Freaks, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, Helder, JukeBlox, KeeLoq, Klear, LANCheck, LINK MD, maXStylus, maXTouch, MediaLB, megaAVR, MOST, MOST logo, MPLAB, OptoLyzer, PIC, picoPower, PICSTART, PIC32 logo, Prochip Designer, QTouch, SAM-BA, SpyNIC, SST, SST Logo, SuperFlash, tinyAVR, UNI/O, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

ClockWorks, The Embedded Control Solutions Company, EtherSynch, Hyper Speed Control, HyperLight Load, IntelliMOS, mTouch, Precision Edge, and Quiet-Wire are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, INICnet, Inter-Chip Connectivity, JitterBlocker, KlearNet, KlearNet logo, memBrain, Mindi, MiWi, motorBench, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICKit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2018, Microchip Technology Incorporated, All Rights Reserved.

ISBN: 978-1-5224-3661-4

Worldwide Sales and Service

AMERICAS

Corporate Office
2355 West Chandler Blvd.
Chandler, AZ 85224-6199
Tel: 480-792-7200
Fax: 480-792-7277
Technical Support:
<http://www.microchip.com/support>
Web Address:
www.microchip.com

Atlanta
Duluth, GA
Tel: 678-957-9614
Fax: 678-957-1455

Austin, TX
Tel: 512-257-3370

Boston
Westborough, MA
Tel: 774-760-0087
Fax: 774-760-0088

Chicago
Itasca, IL
Tel: 630-285-0071
Fax: 630-285-0075

Dallas
Addison, TX
Tel: 972-818-7423
Fax: 972-818-2924

Detroit
Novi, MI
Tel: 248-848-4000

Houston, TX
Tel: 281-894-5983

Indianapolis
Noblesville, IN
Tel: 317-773-8323
Fax: 317-773-5453
Tel: 317-536-2380

Los Angeles
Mission Viejo, CA
Tel: 949-462-9523
Fax: 949-462-9608
Tel: 951-273-7800

Raleigh, NC
Tel: 919-844-7510

New York, NY
Tel: 631-435-6000

San Jose, CA
Tel: 408-735-9110
Tel: 408-436-4270

Canada - Toronto
Tel: 905-695-1980
Fax: 905-695-2078

ASIA/PACIFIC

Australia - Sydney
Tel: 61-2-9868-6733

China - Beijing
Tel: 86-10-8569-7000

China - Chengdu
Tel: 86-28-8665-5511

China - Chongqing
Tel: 86-23-8980-9588

China - Dongguan
Tel: 86-769-8702-9880

China - Guangzhou
Tel: 86-20-8755-8029

China - Hangzhou
Tel: 86-571-8792-8115

China - Hong Kong SAR
Tel: 852-2943-5100

China - Nanjing
Tel: 86-25-8473-2460

China - Qingdao
Tel: 86-532-8502-7355

China - Shanghai
Tel: 86-21-3326-8000

China - Shenyang
Tel: 86-24-2334-2829

China - Shenzhen
Tel: 86-755-8864-2200

China - Suzhou
Tel: 86-186-6233-1526

China - Wuhan
Tel: 86-27-5980-5300

China - Xian
Tel: 86-29-8833-7252

China - Xiamen
Tel: 86-592-2388138

China - Zhuhai
Tel: 86-756-3210040

ASIA/PACIFIC

India - Bangalore
Tel: 91-80-3090-4444

India - New Delhi
Tel: 91-11-4160-8631

India - Pune
Tel: 91-20-4121-0141

Japan - Osaka
Tel: 81-6-6152-7160

Japan - Tokyo
Tel: 81-3-6880-3770

Korea - Daegu
Tel: 82-53-744-4301

Korea - Seoul
Tel: 82-2-554-7200

Malaysia - Kuala Lumpur
Tel: 60-3-7651-7906

Malaysia - Penang
Tel: 60-4-227-8870

Philippines - Manila
Tel: 63-2-634-9065

Singapore
Tel: 65-6334-8870

Taiwan - Hsin Chu
Tel: 886-3-577-8366

Taiwan - Kaohsiung
Tel: 886-7-213-7830

Taiwan - Taipei
Tel: 886-2-2508-8600

Thailand - Bangkok
Tel: 66-2-694-1351

Vietnam - Ho Chi Minh
Tel: 84-28-5448-2100

EUROPE

Austria - Wels
Tel: 43-7242-2244-39
Fax: 43-7242-2244-393

Denmark - Copenhagen
Tel: 45-4450-2828
Fax: 45-4485-2829

Finland - Espoo
Tel: 358-9-4520-820

France - Paris
Tel: 33-1-69-53-63-20
Fax: 33-1-69-30-90-79

Germany - Garching
Tel: 49-8931-9700

Germany - Haan
Tel: 49-2129-3766400

Germany - Heilbronn
Tel: 49-7131-67-3636

Germany - Karlsruhe
Tel: 49-721-625370

Germany - Munich
Tel: 49-89-627-144-0
Fax: 49-89-627-144-44

Germany - Rosenheim
Tel: 49-8031-354-560

Israel - Ra'anana
Tel: 972-9-744-7705

Italy - Milan
Tel: 39-0331-742611
Fax: 39-0331-466781

Italy - Padova
Tel: 39-049-7625286

Netherlands - Drunen
Tel: 31-416-690399
Fax: 31-416-690340

Norway - Trondheim
Tel: 47-7288-4388

Poland - Warsaw
Tel: 48-22-3325737

Romania - Bucharest
Tel: 40-21-407-87-50

Spain - Madrid
Tel: 34-91-708-08-90
Fax: 34-91-708-08-91

Sweden - Gothenberg
Tel: 46-31-704-60-40

Sweden - Stockholm
Tel: 46-8-5090-4654

UK - Wokingham
Tel: 44-118-921-5800
Fax: 44-118-921-5820